NSN 5962-01-273-8046



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-273-8046 **Body Length:** Between 1.435 inches and 1.485 inches **Body Width:** Between 0.515 inches and 0.600 inches **Body Height:** Between 0.140 inches and 0.175 inches **Operating Tempurature Range:** -0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **Features Provided:** Electrostatic sensitive and hermetically sealed and w/enable **Inclosure Material:** Ceramic or metal **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 21 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 6.0 volts power source **Time Rating Per Chacteristic:** 250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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